# NSN 5962-01-158-9908

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### **Body Length:**

Between 1.380 inches and 1.430 inches

# Body Width:

Between 0.580 inches and 0.610 inches

# **Body Height:**

Between 0.080 inches and 0.120 inches

# **Maximum Power Dissipation Rating:**

1000.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Radio terminal set, type an/trc-170

#### **Features Provided:**

Hermetically sealed and programmable and bipolar and w/open collector

#### Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

17 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

5.5 volts power source

#### **Time Rating Per Chacteristic:**

80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Pal

# Test Data Document:

49956-954387 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

28 printed circuit

# Shelf Life:

N/a

#### Unit Of Measure:

# Demilitarization:

Yes - demil/mli

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